

TSC		TS13001							
TO-92		High Voltage NPN Transistor							
 <p>Pin assignment: 1. Emitter 2. Collector 3. Base</p>		<b><math>BV_{CEO} = 400V</math></b> <b><math>BV_{CBO} = 500V</math></b> <b><math>I_C = 0.1A</math></b> <b><math>V_{CE(SAT)}, = 0.5V @ I_C / I_B = 50mA / 10mA</math></b>							
<b>Features</b> ◇ High voltage. ◇ High speed switching		<b>Ordering Information</b> <table border="1"> <thead> <tr> <th>Part No.</th> <th>Packing</th> <th>Package</th> </tr> </thead> <tbody> <tr> <td>TS13001CT</td> <td>Bulk</td> <td>TO-92</td> </tr> </tbody> </table>		Part No.	Packing	Package	TS13001CT	Bulk	TO-92
Part No.	Packing	Package							
TS13001CT	Bulk	TO-92							
<b>Structure</b> ◇ Silicon triple diffused type. ◇ NPN silicon transistor									
<b>Absolute Maximum Rating</b> ( $T_a = 25^\circ C$ unless otherwise noted)									
Parameter	Symbol	Limit	Unit						
Collector-Base Voltage	$V_{CBO}$	500V	V						
Collector-Emitter Voltage	$V_{CEO}$	400V	V						
Emitter-Base Voltage	$V_{EBO}$	9	V						
Collector Current	DC	$I_C$	0.1	A					
	Pulse		0.3						
Collector Power Dissipation	TO-92	$P_D$	0.6	W					
Operating Junction Temperature	$T_J$	+150		$^\circ C$					
Operating Junction and Storage Temperature Range	$T_{STG}$	- 55 to +150		$^\circ C$					

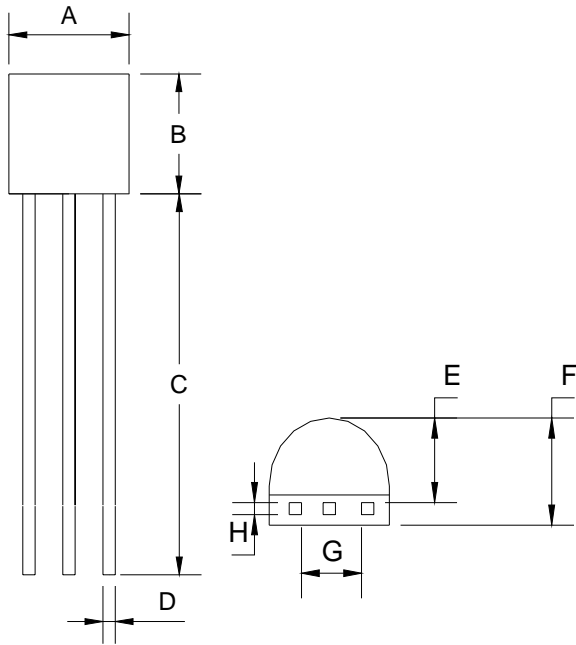
Note: 1. Single pulse,  $P_w = 5mS$ , Duty  $\leq 10\%$

Electrical Characteristics						
Ta = 25 °C unless otherwise noted						
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Collector-Base Voltage	$I_C = 10mA, I_B = 0$	$BV_{CBO}$	500	--	--	V
Collector-Emitter Breakdown Voltage	$I_C = 10mA, I_E = 0$	$BV_{CEO}$	400	--	--	V
Emitter-Base Breakdown Voltage	$I_E = 1mA, I_C = 0$	$BV_{EBO}$	9	--	--	V
Collector Cutoff Current	$V_{CB} = 500V, I_E = 0$	$I_{CBO}$	--	--	100	$\mu A$
Emitter Cutoff Current	$V_{EB} = 7V, I_C = 0$	$I_{EBO}$	--	--	0.01	$\mu A$
Collector-Emitter Saturation Voltage	$I_C / I_B = 50mA / 10mA$	$V_{CE(SAT)}$	--	--	0.5	V
DC Current Gain	$V_{CE} = 5V, I_C = 20mA$	$h_{FE}$	10	--	40	
Output Capacitance	$V_{CB} = 10V, f = 0.1MHz$	$C_{ob}$	--	4	--	pF
Storage Time	$V_{CE} = 250V, I_C = 5 Ib,$ $Ib1=Ib2=40mA$	$t_s$	--	--	2.0	$\mu S$
Fall Time		$t_f$	--	--	0.8	

Note : pulse test: pulse width  $\leq 5mS$ , duty cycle  $\leq 10\%$



## TO-92 Mechanical Drawing



TO-92 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.70	0.169	0.185
B	4.30	4.70	0.169	0.185
C	14.30(typ)		0.563(typ)	
D	0.43	0.49	0.017	0.019
E	2.19	2.81	0.086	0.111
F	3.30	3.70	0.130	0.146
G	2.42	2.66	0.095	0.105
H	0.37	0.43	0.015	0.017